

## Using light to generate order in an exotic material

Physics experiment with ultrafast laser pulses produces a previously unseen phase of matter.

David L. Chandler | MIT News Office November 11, 2019



An artist's impression of a light-induced charge density wave (CDW). The wavy mesh represents distortions of the material's lattice structure caused by the formation of CDWs. Glowing spheres represent photons. In the center, the original CDW is suppressed by a brief pulse of laser light, while a new CDW appears at right angles to the first.

Image: Alfred Zong

https://news.mit.edu/2019/light-orders-exotic-material-1111





**TeraHertz Time-Domain Spectroscopy** 







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- 1 Professor
- 4 Postdocs
- 11 Graduate students



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# Light-induced charge density wave in  $LaTe<sub>3</sub>$

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When electrons in a solid are excited by light, they can alter the free energy landscape and access phases of matter that are out of reach in thermal equilibrium. This accessibility becomes important in the presence of phase competition, when one state of matter is preferred over another by only a small energy scale that, in principle, is surmountable by the excitation. Here, we study a layered compound, LaTe<sub>2</sub>, where a small lattice anisotropy in the a-c plane results in a unidirectional charge density wave (CDW) along the c axis<sup>1,2</sup>. Using ultrafast electron diffraction, we find that, after photoexcitation, the CDW along the c axis is weakened and a different competing CDW along the *a* axis subsequently emerges. The timescales characterizing the relaxation of this new CDW and the reestablishment of the original CDW are nearly identical, which points towards a strong competition between the two orders. The new density wave represents a transient non-equilibrium phase of matter with no equilibrium counterpart, and this study thus provides a framework for discovering similar states of matter that are 'trapped' under equilibrium conditions.



Competition or cooperation between proximal phases

- $-$  <sup>3</sup>He: FM spin fluctuations vs p-wave superfluidity
- 
- 
- - $\rightarrow$  mesoscopic phase separation when ΔE ≤ T









Uehara et al., Nature 399, 560 (1999)

### What is a charge density wave (CDW)?

Usually, conduction electrons in a solid are in a quantum liquid state., i.e., spatially homogeneous.



## Other mechanisms for CDW

※ Excitonic insulator or band-type Jahn-Teller mechanism



X. Zhu et al., PNAS 112, 2367 (2015)



CDW without FSN





※ Saddle point @ EF in quasi-2D materials (VHS)

$$
\epsilon(\mathbf{q}, \omega) = 1 + \chi(\mathbf{q}, \omega) = 1 - V_{\mathbf{q}} \sum_{\mathbf{k}} \frac{n_{\mathbf{k} + \mathbf{q}} - n_{\mathbf{k}}}{\hbar \omega + E_{\mathbf{k} + \mathbf{q}} - E_{\mathbf{k}}}
$$

$$
\sum_{\mathbf{k}} \longrightarrow \int dED(E)
$$

※ Different from charge order caused by nnb Coulomb repulsions not related with phonons , La<sub>0.5</sub>Ca<sub>0.5</sub>MnO<sub>3</sub>, etc.



※ None of the before, still unknown

## Methods

### Sample preparation:

Mechanical exfoliation down to 60 nm checked by AFM,

then transferred to 10-nm-thick  $Si<sub>3</sub>N<sub>4</sub>$  window

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detector: P43 phosphor screen for el

### keV UED @ homelab:

probe e-beam: photoelectron by 4<sup>th</sup> harmonic (260 nm) laser, 26 kV DC acceleration, 270 x 270 μm<sup>2</sup> beam size on a sample (FWHM)

detector: Al-coated P46 phosphor screen, CCD (PI-MAX II)



Ultrafast dynamics of CDW peaks of LaTe<sub>3</sub>





Perfect anti-correlation between a-CDW and c-CDW intensity changes<br>decay time  $\tau_a \approx$  recovery time  $\tau_c \rightarrow$  same mechanism & phase competition decay time  $\tau_a \approx$  recovery time  $\tau_c \rightarrow$  same mechanism & phase competition







Transient nature of  $\mathsf{q}_{\mathsf{a}}$  in LaTe $_3$  different from ground state  $\mathsf{q}_{\mathsf{a}}$  in other RETe $_3$ 





If c-CDW melts, gap closing causes competition .



Origin of transient CDW: topological defect/anti-defect pair generation c-CDW is topologically inhibited, which allows a-CDW.

Ginzburg-Landau free energy density

$$
\mathcal{F} = r_c |\psi_c|^2 + \frac{\beta_c |\psi_c|^4}{2} + \kappa_c |\nabla_r \psi_c|^2 + r_c |\psi_c|^2 + \frac{\beta_c |\psi_c|^4}{2} + \kappa_c |\nabla_r \psi_c|^2 + \eta |\psi_c|^2 |\psi_a|^2
$$
  
Minimize 
$$
\int d^2 \mathbf{r} \mathcal{F}(\mathbf{r})
$$

$$
\rightarrow -\kappa_c \nabla_r^2 \psi_c + r_c \psi_c + \beta_c |\psi_c|^2 \psi_c + \eta |\psi_a|^2 \psi_c = 0
$$

$$
-\kappa_a \nabla_r^2 \psi_a + r_a \psi_a + \beta_a |\psi_a|^2 \psi_a + \eta |\psi_c|^2 \psi_a = 0
$$
by putting 
$$
\psi_c(r, \phi) = \psi_c^\infty f(r) e^{im\phi}
$$
 and 
$$
\psi_a(r, \phi) = \psi_a^\infty g(r)
$$